

isc N-Channel MOSFET Transistor

TK5P65W

• FEATURES

- Low drain-source on-resistance: R_{DS}(on) ≤1.22mΩ.
- Enhancement mode:
 Vth =2.5 to 3.5V (VDS = 10 V, ID=0.17mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



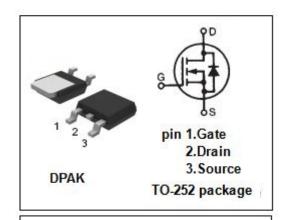
· Switching Voltage Regulators

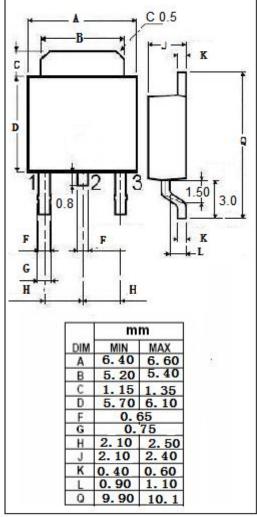
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|-----------|------|
| V _{DSS} | Drain-Source Voltage | 650 | V |
| V _{GS} | Gate-Source Voltage | ±30 | V |
| I _D | Drain Current-Continuous | 5.2 | A |
| I _{DM} | Drain Current-Single Pulsed | 20.8 | A |
| P _D | Total Dissipation @T _C =25℃ | 60 | W |
| Tj | Max. Operating Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature | e -55~150 | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|------------------------------------|------|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 2.09 | °C/W |







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | МАХ | UNIT |
|---------------------|--------------------------------|--|-----|-----|------|------------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D =10mA | 650 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =10V; I _D =0.17mA | 2.5 | | 3.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D =2.6A | | | 1.22 | Ω |
| lgss | Gate-Source Leakage Current | V _{GS} = ±30V;V _{DS} = 0V | | | ±1 | μ А |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =650V; V _{GS} = 0V | | | 10 | μА |
| V _{SDF} | Diode forward voltage | I _{DR} =5.2A, V _{GS} = 0 V | | | 1.7 | V |



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